

3.3V CMOS OCTAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS AND 5 VOLT TOLERANT I/O

IDT74LVC2245A

FEATURES:

- 0.5 MICRON CMOS Technology
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- CMOS power levels (0.4μ W typ. static)
- · Rail-to-rail output swing for increased noise margin
- All inputs, outputs, and I/O are 5V tolerant
- · Available in QSOP package

DRIVE FEATURES:

- Balanced Output Drivers: ±12mA (B Port)
- · High Output Drivers: ±24mA (A Port)

APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- · Data communication and telecommunication systems

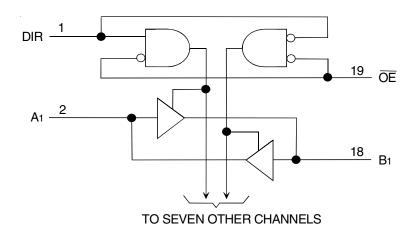
DESCRIPTION:

This bus transceiver is built using advanced dual metal CMOS technology. The LVC2245A device is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device so the buses are effectively isolated.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V environment.

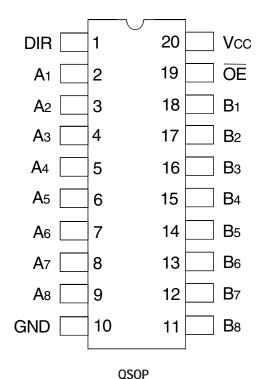
The LVC2245A has series resistors in the device output structure of the "B" port which will significantly reduce line noise when used with light loads. The driver has been designed to drive ± 12 mA at the designated threshold lovels

FUNCTIONAL BLOCK DIAGRAM



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PIN CONFIGURATION



TOP VIEW

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM	Terminal Voltage with Respect to GND	-0.5 to +6.5	V
Tstg	Storage Temperature	-65 to +150	°C
Іоит	DC Output Current	-50 to +50	mA
lik lok	Continuous Clamp Current, VI < 0 or Vo < 0	-50	mA
lcc Iss	Continuous Current through each Vcc or GND	±100	mA

NOTE:

Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause
permanent damage to the device. This is a stress rating only and functional operation
of the device at these or any other conditions above those indicated in the operational
sections of this specification is not implied. Exposure to absolute maximum rating
conditions for extended periods may affect reliability.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	4.5	6	pF
Соит	Output Capacitance	Vout = 0V	5.5	8	pF
Cı/o	I/O Port Capacitance	VIN = 0V	6.5	8	pF

NOTE:

1. As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description	
ŌĒ	Output Enable Input (Active LOW)	
DIR	Direction Control Output	
Ax	A x Side A Inputs or 3-State Outputs	
Вх	Side B Inputs or 3-State Outputs	

FUNCTION TABLE(1)

Inputs			
ŌĒ	DIR	Outputs	
L	L	B Data to A Bus	
L	Н	A Data to B Bus	
Н	Х	Isolation	

NOTE:

1. H = HIGH Voltage Level

X = Don't Care

L = LOW Voltage Level

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: $TA = -40^{\circ}C$ to $+85^{\circ}C$

Symbol	Parameter	Test Cor	nditions	Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	V
		Vcc = 2.7V to 3.6V		2	_	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		_	_	0.7	V
		Vcc = 2.7V to 3.6V		_	_	0.8	
Іін	Input Leakage Current	Vcc = 3.6V	VI = 0 to 5.5V		_	±5	μΑ
lıL							
lozh	High Impedance Output Current	Vcc = 3.6V	Vo = 0 to 5.5V	_	_	±10	μΑ
lozl	(3-State Output pins)						
loff	Input/Output Power Off Leakage	$Vcc = 0V$, $Vin or Vo \le 5.5V$		_	_	±50	μΑ
Vik	Clamp Diode Voltage	Vcc = 2.3V, IIN = -18mA		_	-0.7	-1.2	V
VH	Input Hysteresis	Vcc = 3.3V		T -	100	_	mV
ICCL	Quiescent Power Supply Current	Vcc = 3.6V	VIN = GND or Vcc	<u> </u>	_	10	μA
ICCH ICCZ			$3.6 \le \text{Vin} \le 5.5 \text{V}^{(2)}$	+		10	
Δlcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, other in		_	_	500	μА

NOTES:

- 1. Typical values are at Vcc = 3.3V, +25°C ambient.
- 2. This applies in the disabled state only.

OUTPUT DRIVE CHARACTERISTICS (A PORT)

Symbol	Parameter	Test Con	ditions ⁽¹⁾	Min.	Max.	Unit
Voh	Output HIGH Voltage	Vcc = 2.3V to 3.6V	IOH = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	IOH = -6mA	2	_	
		Vcc = 2.3V	Iон = - 12mA	1.7	_	
		Vcc = 2.7V		2.2	_	
		Vcc = 3V	1	2.4	_	ľ
		Vcc = 3V	IOH = - 24mA	2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	_	0.2	V
		Vcc = 2.3V	IoL = 6mA	_	0.4	
			IoL = 12mA	_	0.7	
		Vcc = 2.7V	IoL = 12mA	_	0.4	
		VCC = 3V	IoL = 24mA	_	0.55	

NOTE:

^{1.} VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = - 40°C to + 85°C.

OUTPUT DRIVE CHARACTERISTICS (B PORT)

Symbol	Parameter	Test Cor	nditions ⁽¹⁾	Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = 2.3V to 3.6V	IOH = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	IOH = -4mA	1.9	_	
			IOH = -6mA	1.7	_	
		Vcc = 2.7V	IOH = -4mA	2.2	_	
			IOH = -8mA	2	_	
		Vcc = 3V	IOH = -6mA	2.4	_	
			IOH = - 12mA	2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	_	0.2	V
		Vcc = 2.3V	IoL = 4mA	_	0.4	
			IoL = 6mA	_	0.55	
		Vcc = 2.7V	IoL = 4mA	_	0.4	
			IoL = 8mA	_	0.6	
		Vcc = 3V	IOL = 6mA	_	0.55	
			IoL = 12mA	_	0.8	

NOTE:

OPERATING CHARACTERISTICS, Vcc = 3.3V ± 0.3V, Ta = 25°C

Symbol	Parameter	Test Conditions	Typical	Unit
CPD	Power Dissipation Capacitance per Transceiver Outputs enabled	CL = 0pF, f = 10Mhz	48	pF
CPD	Power Dissipation Capacitance per Transceiver Outputs disabled		4	

SWITCHING CHARACTERISTICS (A PORT)(1)

		Vcc =	2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
tPLH	Propagation Delay	_	7.3	1.5	6.3	ns
tphl.	Bx to Ax					
tpzh	Output Enable Time	_	9.5	1.5	8.5	ns
tpzl	OE to Ax					
tphz	Output Disable Time	_	8.5	1.7	7.5	ns
tplz	OE to Ax					
tsk(o)	Output Skew ⁽²⁾	_	_	_	500	ps

NOTES:

- 1. See TEST CIRCUITS AND WAVEFORMS. TA = -40°C to +85°C.
- 2. Skew between any two outputs of the same package and switching in the same direction.

^{1.} VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = - 40°C to + 85°C.

SWITCHING CHARACTERISTICS (B PORT)(1)

		Vcc =	2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
tplh	Propagation Delay	_	8.1	1.5	7.1	ns
tphl	Ax to Bx					
tpzh	Output Enable Time	_	10	1.5	9	ns
tpzL	OE to Bx					
tphz	Output Disable Time	_	9.2	1.7	8.2	ns
tplz	OE to Bx					
tsk(o)	Output Skew ⁽²⁾	_	_	_	500	ps

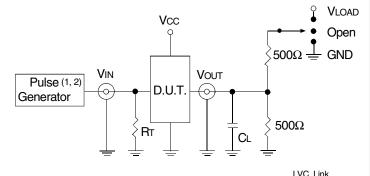
NOTES:

- 1. See TEST CIRCUITS AND WAVEFORMS. TA = -40° C to $+85^{\circ}$ C.
- 2. Skew between any two outputs of the same package and switching in the same direction.

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

Symbol	$Vcc^{(1)} = 3.3V \pm 0.3V$	$Vcc^{(1)}=2.7V$	Vcc ⁽²⁾ = 2.5V±0.2V	Unit
VLOAD	6	6	2 x Vcc	V
VIH	2.7	2.7	Vcc	V
VT	1.5	1.5	Vcc / 2	V
VLZ	300	300	150	mV
VHZ	300	300	150	mV
CL	50	50	30	pF



Test Circuit for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

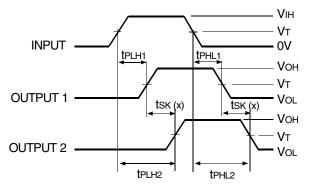
RT = Termination resistance: should be equal to ZouT of the Pulse Generator.

NOTES:

- 1. Pulse Generator for All Pulses: Rate \leq 10MHz; tr \leq 2.5ns; tr \leq 2.5ns.
- 2. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	VLOAD
Disable High Enable High	GND
All Other Tests	Open

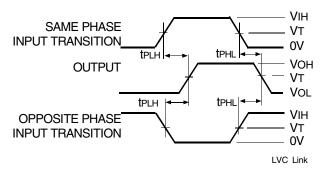


tsk(x) = |tPLH2 - tPLH1| or |tPHL2 - tPHL1|

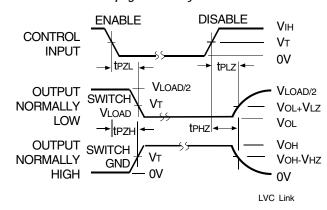
Output Skew - tsk(x) LVC Link

NOTES:

- 1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.
- 2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



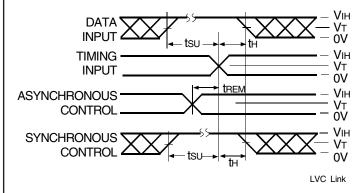
Propagation Delay



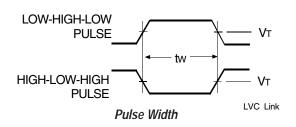
Enable and Disable Times

NOTE:

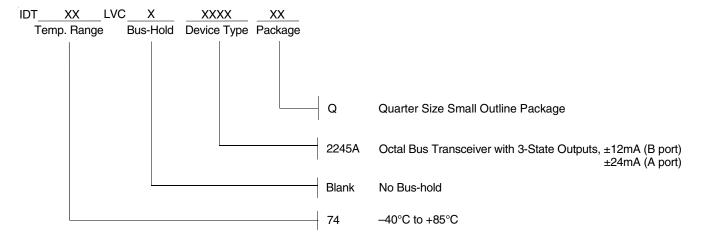
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.



Set-up, Hold, and Release Times



ORDERING INFORMATION





CORPORATE HEADQUARTERS

6024 Silver Creek Valley Road San Jose, CA 95138 for SALES: 800-345-7015 or 408-284-8200 fax: 408-284-2775 www.idt.com for Tech Support: logichelp@idt.com